Vishay Semiconductors

High Speed Infrared Emitting Diodes, 850 nm, Surface Emitter Technology

VSMY2850RG



DESCRIPTION

As part of the <u>SurfLight</u>^{IM} portfolio, the VSMY2850 series are infrared, 850 nm emitting diodes based on GaAlAs surface emitter chip technology with extreme high radiant intensities, high optical power and high speed, molded in clear, untinted plastic packages (with lens) for surface mounting (SMD).

APPLICATIONS

- Miniature light barrier
- Photointerrupters
- Optical switch
- Emitter source for proximity sensors
- IR illumination

FEATURES

- Package type: surface-mount
- Package form: GW, RGW
- Dimensions (L x W x H in mm): 2.3 x 2.3 x 2.8
- Peak wavelength: $\lambda_p = 850 \text{ nm}$
- High reliability
- · High radiant power
- · Very high radiant intensity
- Angle of half intensity: $\phi = \pm 10^{\circ}$
- · Suitable for high pulse current operation
- Terminal configurations: gullwing or reverse gullwing
- Package matches with detector VEMD2500X01 series
- Floor life: 4 weeks, MSL 2a, according to J-STD-020
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

PRODUCT SUMMARY				
COMPONENT	l _e (mW/sr)	φ (deg)	λ _P (nm)	t _r (ns)
VSMY2850RG	125	± 10	850	10
VSMY2850G	125	± 10	850	10

Note

Test conditions see table "Basic Characteristics"

ORDERING INFORMATION				
ORDERING CODE	DERING CODE PACKAGING		PACKAGE FORM	
VSMY2850RG	Tape and reel	MOQ: 6000 pcs, 6000 pcs/reel	Reverse gullwing	
VSMY2850G	Tape and reel	MOQ: 6000 pcs, 6000 pcs/reel	Gullwing	

Note

• MOQ: minimum order quantity



RoHS

COMPLIANT

GREEN

(5-2008)



VSMY2850G



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ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V _R	5	V	
Forward current		١ _F	100	mA	
Peak forward current	$t_p/T = 0.5, t_p = 100 \ \mu s$	I _{FM}	200	mA	
Surge forward current	t _p = 100 μs	I _{FSM}	1	A	
Power dissipation		Pv	190	mW	
Junction temperature		Tj	100	°C	
Operating temperature range		T _{amb}	-40 to +85	°C	
Storage temperature range		T _{stg}	-40 to +100	°C	
Soldering temperature	According to Fig. 10, J-STD-020	T _{sd}	260	°C	
Thermal resistance junction-to-ambient	EIA / JESD51	R _{thJA}	250	K/W	

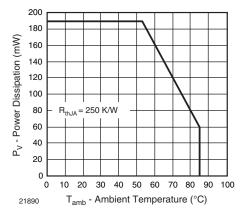


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

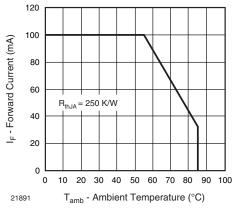


Fig. 2 - Forward Current Limit vs. Ambient Temperature

	$(T_{amb} = 25 \ ^{\circ}C, unless otherwis)$					
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	V _F	-	1.6	1.9	V
	$I_F = 1 \text{ A}, t_p = 100 \ \mu s$	V _F	-	2.8	-	V
Temperature coefficient of V_F	I _F = 100 mA	TK _{VF}	-	-1.5	-	mV/K
Reverse current		I _R	Not designed for reverse operation			μA
Junction capacitance	$V_R = 0 V, f = 1 MHz, E = 0 mW/cm^2$	CJ	-	50	-	pF
Radiant intensity	I _F = 100 mA, t _p = 20 ms	l _e	70	125	210	mW/sr
	$I_F = 1 \text{ A}, t_p = 100 \ \mu \text{s}$	l _e	-	1000	-	mW/sr
Radiant power	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	фе	-	55	-	mW
Temperature coefficient of radiant power	I _F = 100 mA	ΤΚφ _e	-	-0.12	-	%/K
Angle of half intensity		φ	-	± 10	-	deg
Peak wavelength	I _F = 100 mA	λp	840	850	870	nm
Spectral bandwidth	I _F = 30 mA	Δλ	-	30	-	nm
Temperature coefficient of λ_p	I _F = 30 mA	ΤΚλ _p	-	0.25	-	nm/K
Rise time	I _F = 100 mA, 10 % to 90 %	t _r	-	10	-	ns
Fall time	I _F = 100 mA, 10 % to 90 %	t _f	-	10	-	ns

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BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

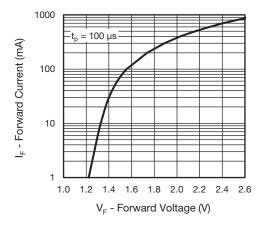


Fig. 3 - Forward Current vs. Forward Voltage

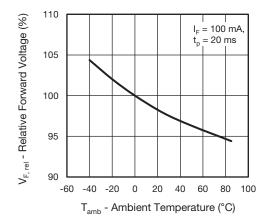


Fig. 4 - Relative Forward Voltage vs. Ambient Temperature

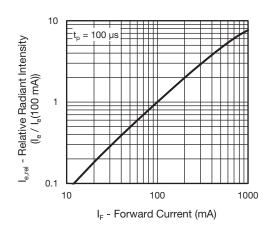


Fig. 5 - Relative Radiant Intensity vs. Forward Current

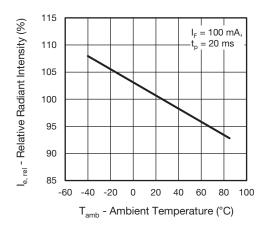


Fig. 6 - Relative Radiant Intensity vs. Ambient Temperature

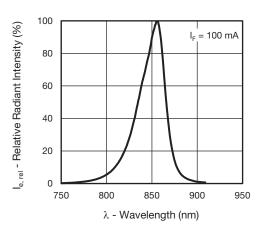


Fig. 7 - Relative Radiant Intensity vs. Wavelength

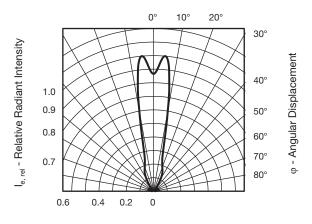


Fig. 8 - Relative Radiant Intensity vs. Angular Displacement

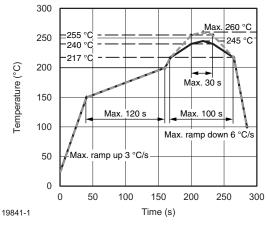
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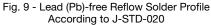
3 For technical questions, contact: <u>emittertechsupport@vishay.com</u>

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SOLDER PROFILE





VSMY2850RG, VSMY2850G

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DRYPACK

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

FLOOR LIFE

Floor life (time between soldering and removing from MBB) must not exceed the time indicated on MBB label:

Floor life: 4 weeks

Conditions: $T_{amb} < 30\ ^\circ C,\ RH < 60\ \%$

Moisture sensitivity level 2a, according to J-STD-020.

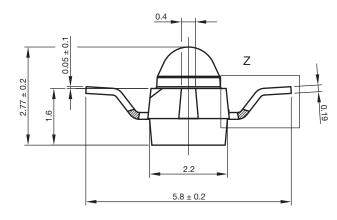
DRYING

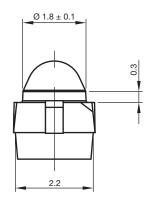
In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or label. Devices taped on reel dry using recommended conditions 192 h at 40 °C (+ 5 °C), RH < 5 %.

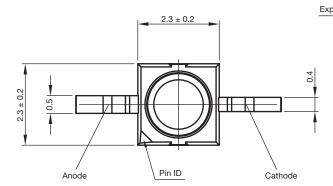


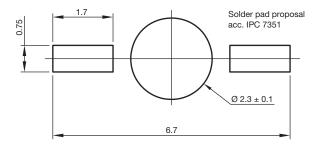
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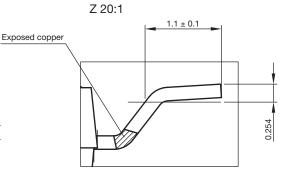
PACKAGE DIMENISONS in millimeters: VSMY2850RG





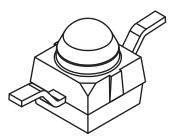








Not indicated tolerances ± 0.1

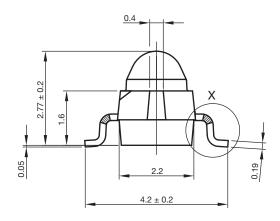


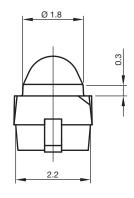
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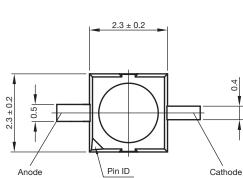


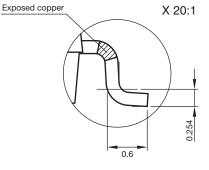
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PACKAGE DIMENSIONS in millimeters: VSMY2850G



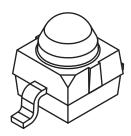


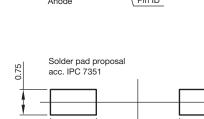


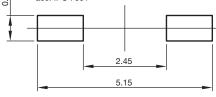




Not indicated tolerances ± 0.1







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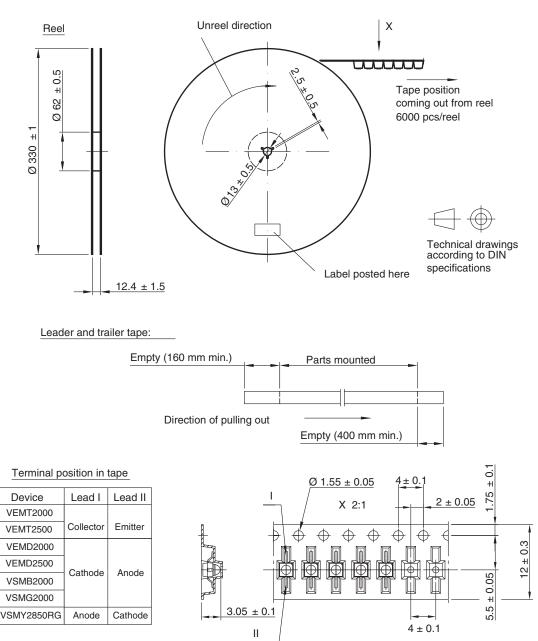
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TAPING AND REEL DIMENSIONS in millimeters: VSMY2850RG



Drawing-No.: 9.800-5100.01-4 Issue: 2; 18.03.10 ²¹⁵⁷²

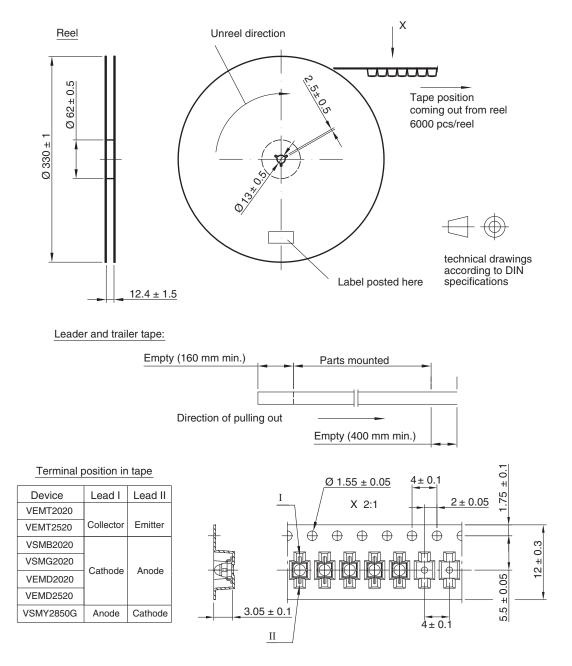
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TAPING AND REEL DIMENSIONS in millimeters: VSMY2850G



Drawing-No.: 9.800-5091.01-4 Issue: 3; 18.03.10 21571



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